BEST AVAILABLE COPY Page No.: 1 of: 2 Serial No. Docket No.: 904.0101.U2(US) 824,959 Applicant(s): Xiao et al. Group: 2818 Class Name of Patentee or Applicant Sub-class Berger et al. 324 244 Gallagher et al. > 11-1998 365 173 12-2002 Kamiguchi et al. ~ 428 692 Carey et al. 🗸 360 324.12 Sato et al. 148 276 Noguchi et al. 🗸 360 113 Tiernan et al. 324 238 Ghoshal et al. 324 750 Ueda et al. 324 751 Onuki et al. 250 306 Wikswo, Jr. et al. 324 258 Gallagher et al. / 365 173 Fontana, Jr. et al. 360 113 Tsuge 428 678 Parkin 324 252 Name Of Patentee of Applicant Translation? Yes/No/n/a

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INFORMATION DISCLOSURE

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